TOSHIBA

2SC2099

Unit in mm

TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

2 S C 2 0 9 9

2~30MHz SSB LINEAR POWER AMPLIFIER APPLICATIONS (LOW SUPPLY VOLTAGE USE)

Specified 12.5V, 28MHz Characteristics

Output Power : Po=20WpEp (Min.)
 Power Gain : G_p=12dB (Min.)
 Collector Efficiency : η_C=35% (Min.)
 Intermodulation Distortion : IMD = -30dB (Max.)

MAXIMUM RATINGS (Tc = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	v_{CBO}	40	V
Collector-Emitter Voltage	VCES	40	V
Collector-Emitter Voltage	v_{CEO}	18	V
Emitter-Base Voltage	$V_{ m EBO}$	4	V
Collector Current	$I_{\mathbf{C}}$	6	A
Collector Power Dissipation	PC	60	W
Junction Temperature	T_{j}	175	°C
Storage Temperature Range	$T_{ m stg}$	-65~175	°C

JEDEC —

TOSHIBA 2-10H1A

Weight: 4.0g

ELECTRICAL CHARACTERISTICS (Tc = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector-Emitter Breakdown Voltage	V _(BR) CEO	$I_{C} = 50 \text{mA}, I_{B} = 0$	18		Let.	V
Collector-Emitter Breakdown Voltage	V _(BR) CES	$I_C=50mA, V_{EB}=0$	40	0.49	T-9-	V
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	$I_E=1mA$, $I_C=0$	4	_	_	V
DC Current Gain	hFE	$V_{CE}=5V, I_{C}=5A$ *	20	_	185	
Transition Frequency	${ m f_T}$	$V_{CE} = 5V$, $I_{C} = 0.5A$	_	100	_	MHz
Collector Output Capacitance	C _{ob}	$V_{CB} = 12.5V, I_{E} = 0$ f = 1MHz	_	_	250	pF
Power Gain	G_{p}	$V_{CC} = 12.5V, f_1 = 28.000$	12.0	_	_	dB
Input Power	Pi	MHz, $f_2 = 28.001$ MHz	_	_	1.2	$W_{ m PEP}$
Collector Efficiency	$\eta_{\mathbf{C}}$	$I_{ m idle}$ = 25mA	35	45		%
Intermodulation Distortion	IMD	$Po = 20W_{PEP}$ (Fig.)	_	_	-30	dB
Series Equivalent Input Impedance	Zin	V_{CC} =12.5V, f_1 =28.000 MHz, f_2 =28.001MHz P_0 =20W _{PEP}	= 4 2	1.1 -j0.25	zsc.	Ω
Series Equivalent Output Impedance	Z _{out}		F_W	$3.0 \\ -j0.75$	_	Ω

^{*} Pulse Test: Pulse Width $\leq 100 \mu$ s, Duty Cycle $\leq 3\%$

CAUTION

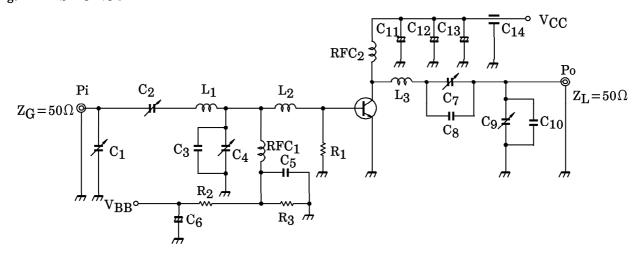
f.dzsc.com

Beryllia Ceramics is used in this product. The dust or vapor can be dangerous to humans. Do not break, cut, crush or dissolve chemically. Dispose of this product properly according to law. Do not intermingle with normal industrial or domestic waste.

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Fig. Pi TEST CIRCUIT

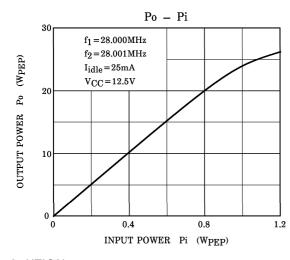


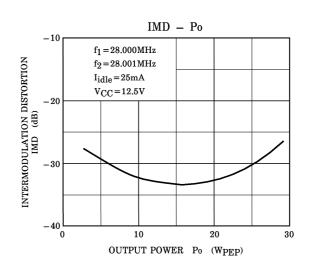
 $C_1, C_2, C_4, C_7 : 7 \sim 150 pF$ L_1 : ϕ 0.8 ENAMEL COATED COPPER WIRE, 9ID, 6T C₃ C₅ C₆ : 250pF : ϕ 1 SILVER PLATED COPPER WIRE, 9ID, 2T L_3 $: 0.4 \mu F$: ϕ 1.5 ENAMEL COATED COPPER WIRE, 9ID, 5T : $100 \mu \text{F} 10 \text{WV}$ RFC₁: ϕ 0.8 ENAMEL COATED COPPER WIRE, 9ID, 20T C₈ RFC_2 : $\phi 1.5$ ENAMEL COATED COPPER WIRE, 12ID, 15T : 150pF

: 10~200pF R_1 C₉ : $5.6\Omega (1/2W)$: 600pF C_{10} R_2 $: 5\Omega (5W)$ $C_{11}, C_{12} : 22 \mu F 35WV$ R_3 : $1.5\Omega (10W)$

 C_{13}^{--} : $0.04 \mu F$: 1000pF C_{14}

(FEED THROUGH)





CAUTION

These are only typical curves and devices are not necessarily guaranteed at these curves.

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